74AHC273-Q100; 74AHCT273-Q100

Octal D-type flip-flop with reset; positive-edge trigger

Rev. 2 — 23 September 2020 Product data sheet

1. General description

The 74AHC273-Q100; 74AHCT273-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7-A.

The 74AHC273-Q100; 74AHCT273-Q100 has eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common clock (CP) and master reset ($\overline{\text{MR}}$) inputs, load and reset (clear) all flip-flops simultaneously. The state of each D input, one set-up time before the LOW-to-HIGH clock transition, is transferred to the corresponding output (Qn) of the flip-flop. All outputs will be forced LOW, independent of clock or data inputs, by a LOW on the $\overline{\text{MR}}$ input.

The device is useful for applications where only the true output is required and the clock and master reset are common to all storage elements.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Inputs accept voltages higher than V_{CC}
- · Ideal buffer for MOS microcontroller or memory
- Common clock and master reset
- Input levels:
 - For 74AHC273-Q100: CMOS level
 - For 74AHCT273-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

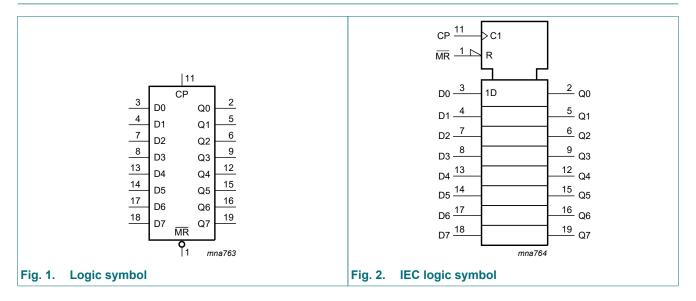


3. Ordering information

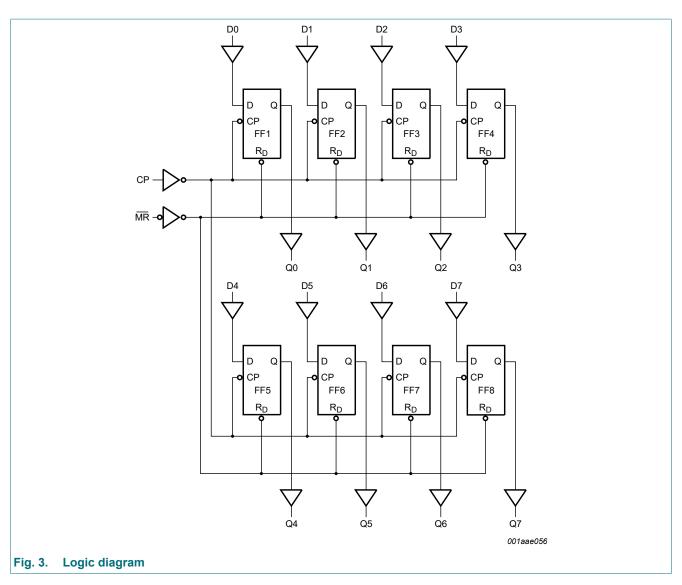
Table 1. Ordering information

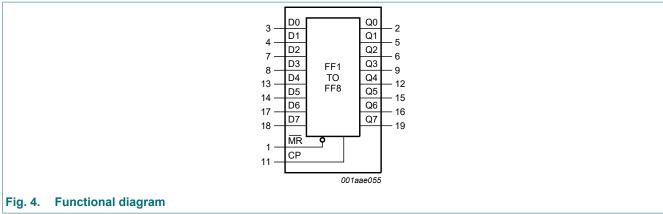
Type number	Package									
	Temperature range	Name	Description	Version						
74AHC273D-Q100	-40 °C to +125 °C	SO20 plastic small outline package; 20 leads;		SOT163-1						
74AHCT273D-Q100	-		body width 7.5 mm							
74AHC273PW-Q100	-40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads;	SOT360-1						
74AHCT273PW-Q100			body width 4.4 mm							
74AHC273BQ-Q100	-40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal	SOT764-1						
74AHCT273BQ-Q100			enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm							

4. Functional diagram



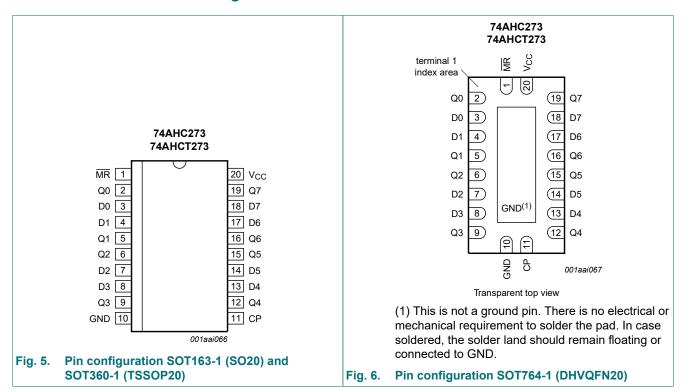
Product data sheet





5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Table 2. I ill description		
Symbol	Pin	Description
MR	1	master reset input (active LOW)
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	2, 5, 6, 9, 12, 15, 16, 19	flip-flop output
D0, D1, D2, D3, D4, D5, D6, D7	3, 4, 7, 8, 13, 14, 17, 18	data input
GND	10	ground (0 V)
CP	11	clock input (LOW-to-HIGH edge-triggered)
V _{CC}	20	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition;

 \uparrow = LOW-to-HIGH; X = don't care.

Operating mode	Control		Input	Output
	MR	СР	Dn	Qn
Reset (clear)	L	Х	Х	L
Load '1'	Н	↑	h	Н
Load '0'	Н	↑	I	L

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	[1]	-20	-	mA
I _{OK}	output clamping current	V_{O} < -0.5 V or V_{O} > V_{CC} + 0.5 V	[1]	-20	+20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-25	+25	mA
Icc	supply current			-	+75	mA
I _{GND}	ground current			-75	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions 74AHC273-Q100		74AHCT273-Q100			Unit		
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	-	-	100	-	-	-	ns/V
	fall rate	V _{CC} = 5.0 V ± 0.5 V	-	-	20	-	-	20	ns/V

^[2] For SOT163-1 (SO20) package: P_{tot} derates linearly with 12.3 mW/K above 109 °C. For SOT360-1 (TSSOP20) package: P_{tot} derates linearly with 10.0 mW/K above 100 °C. For SOT764-1 (DHVQFN20) package: P_{tot} derates linearly with 12.9 mW/K above 111 °C.

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC2	73-Q100		'							
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -50 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -50 μA; V _{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I _O = -50 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V_{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 50 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
l _l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	4.0	-	40	-	80	μΑ
C _I	input capacitance		-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHCT	273-Q100									
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	Ι _Ο = -50 μΑ	4.4	-	-	4.4	-	4.4	-	V
		I _O = -8.0 mA	3.94	-	-	3.80	-	3.70	-	V
V _{OL} LOW-level		$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
l _l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	4.0	-	40	-	80	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other pins at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
C _I	input capacitance		-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
74AHC27	73-Q100									
t _{pd}	propagation	CP to Qn; see Fig. 7 [2]								
	delay	V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	6.0	13.6	1.0	16.0	1.0	17.0	ns
		C _L = 50 pF	-	8.6	17.1	1.0	19.5	1.0	21.5	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.2	9	1.0	10.5	1.0	11.5	ns
		C _L = 50 pF	-	6.0	11.0	1.0	12.5	1.0	14.0	ns
		MR to Qn; see Fig. 8 [3]								
		V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	5.1	13.6	1.0	16.0	1.0	17.0	ns
		C _L = 50 pF	-	7.3	17.1	1.0	19.5	1.0	21.5	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	3.7	8.5	1.0	10.0	1.0	11.0	ns
		C _L = 50 pF	-	5.3	10.5	1.0	12.0	1.0	13.5	ns

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
f _{max}	maximum	see Fig. 7								
	frequency	V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	75	120	-	65	-	65	-	MHz
		C _L = 50 pF	50	75	-	45	-	45	-	MHz
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	120	165	-	100	-	100	-	MHz
		C _L = 50 pF	80	110	-	70	-	70	-	MHz
t _W pu	pulse width	CP HIGH or LOW; see Fig. 7								
		V _{CC} = 3.0 V to 3.6 V	5.0	-	-	6.5	-	6.5	-	ns
		V _{CC} = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
		MR LOW; see Fig. 8								
		V _{CC} = 3.0 V to 3.6 V	5.0	-	-	6.0	-	6.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	Dn to CP; see Fig. 9								
		V _{CC} = 3.0 V to 3.6 V	3.0	-	-	3.0	-	3.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	3.0	-	-	3.0	-	3.0	-	ns
t _h	hold time	Dn to CP; see Fig. 9								
		V _{CC} = 3.0 V to 3.6 V	1.0	-	-	1.0	-	1.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	1.0	-	-	1.0	-	1.0	-	ns
t _{rec}	recovery	MR to CP; see Fig. 8								
	time	V _{CC} = 3.0 V to 3.6 V	2.5	-	-	2.5	-	2.5	-	ns
		V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}$; $V_I = \text{GND to } V_{CC}$ [4]	-	14	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	1
74AHCT	273-Q100; V _C	_C = 4.5 V to 5.5 V		<u>'</u>			'			•
t _{pd}		CP to Qn; see Fig. 7 [2]								
	delay	C _L = 15 pF	-	4.0	7.5	1.0	8.8	1.0	9.5	ns
		C _L = 50 pF	-	5.8	9.2	1.0	10.5	1.0	11.5	ns
		MR to Qn; see Fig. 8 [3]								
		C _L = 15 pF	-	3.9	10.0	1.0	11.6	1.0	12.5	ns
		C _L = 50 pF	-	5.6	11.0	1.0	12.6	1.0	14.0	ns
f _{max} maxii	maximum	see Fig. 7								
	frequency	C _L = 15 pF	75	120	-	65	-	65	-	MHz
		C _L = 50 pF	50	75	-	45	-	45	-	MHz
t _W	pulse width	CP HIGH or LOW; see Fig. 7	5.0	-	-	6.5	-	6.5	-	ns
		MR LOW; see Fig. 8	5.0	-	-	6.0	-	6.0	-	ns
t _{su}	set-up time	Dn to CP; see Fig. 9	3.0	-	-	3.0	-	3.0	-	ns
t _h	hold time	Dn to CP; see Fig. 9	1.0	-	-	1.0	-	1.0	-	ns
t _{rec}	recovery time	MR to CP; see Fig. 8	2.5	-	-	2.5	-	2.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}$; $V_i = \text{GND to } V_{CC}$ [4]	-	18	-	-	-	-	-	pF

- Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$ and $V_{CC} = 5.0 \text{ V}$).
- t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3]
- t_{pd} is the same as t_{PHL} only. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

fo = output frequency in MHz;

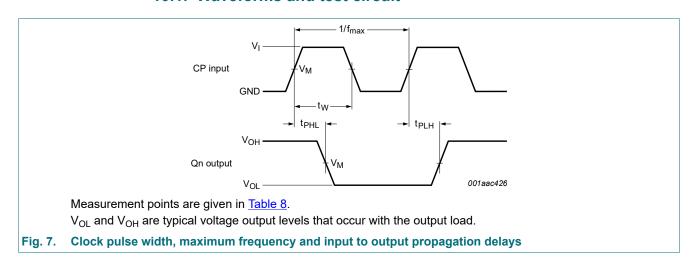
C_L = output load capacitance in pF;

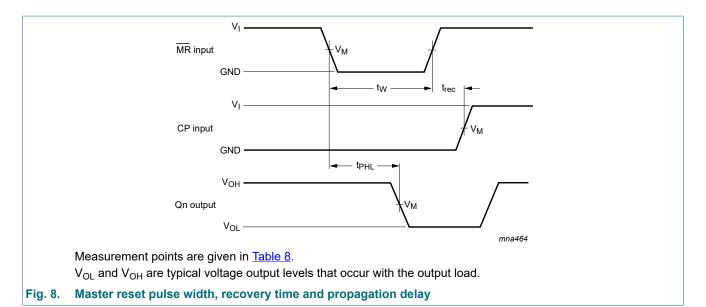
V_{CC} = supply voltage in V;

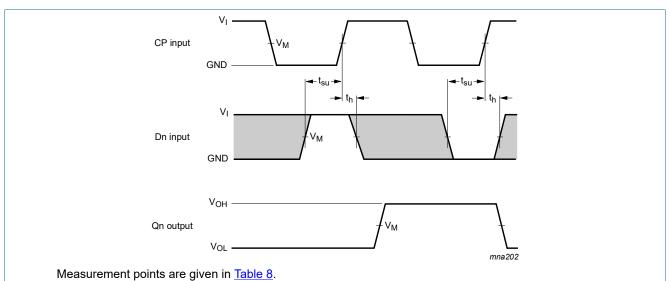
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

10.1. Waveforms and test circuit







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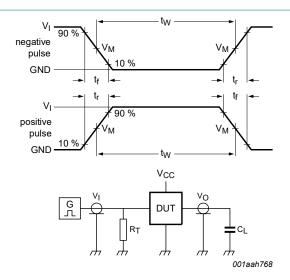
The shaded areas indicate when the input is permitted to change for predictable output performance.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 9. Data set-up and hold times

Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74AHC273-Q100	0.5 x V _{CC}	0.5 x V _{CC}
74AHCT273-Q100	1.5 V	0.5 x V _{CC}



Test data is given in Table 9.

Definitions test circuit:

 R_T = termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = load capacitance including jig and probe capacitance.

Fig. 10. Test circuit for measuring switching times

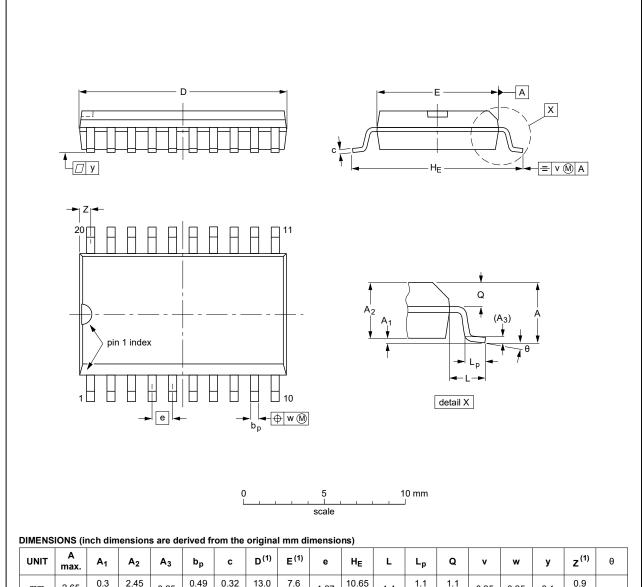
Table 9. Test data

Туре	Input L		Load	Test
	VI	t _r , t _f	CL	
74AHC273-Q100	V _{CC}	≤ 3.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74AHCT273-Q100	3.0 V	≤ 3.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

11. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



u	INIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
	mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
in	ches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

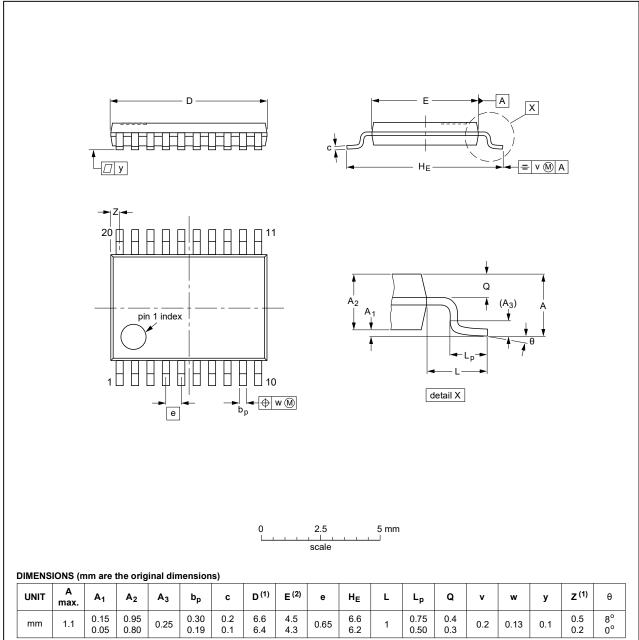
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013				99-12-27 03-02-19	

Fig. 11. Package outline SOT163-1 (SO20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT360-1		MO-153				99-12-27 03-02-19

Fig. 12. Package outline SOT360-1 (TSSOP20)

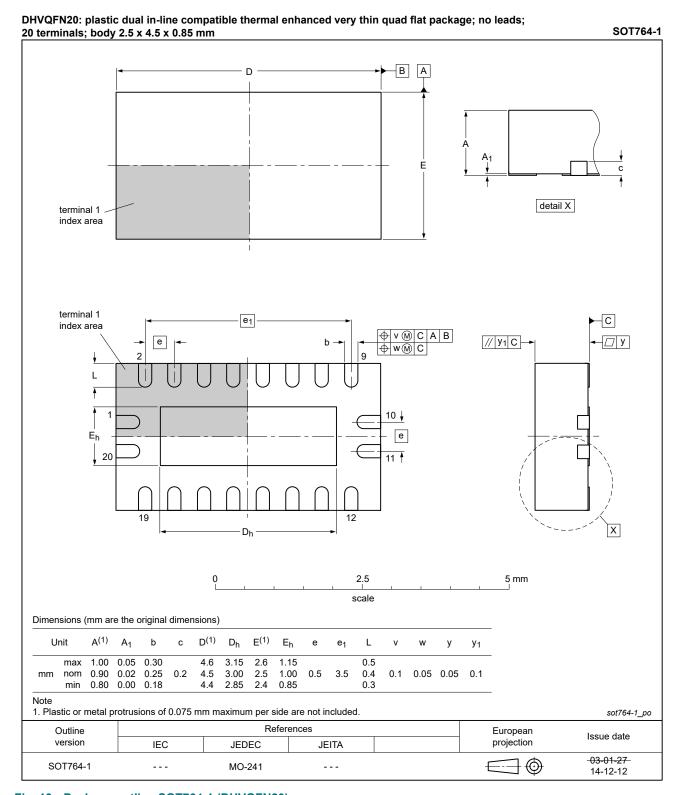


Fig. 13. Package outline SOT764-1 (DHVQFN20)

12. Abbreviations

Table 10. Abbreviations

Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
LSTTL	Low-power Schottky Transistor-Transistor Logic			
MIL	Military			
MM	Machine Model			
MOS Metal-Oxide Semiconductor				

13. Revision history

Table 11. Revision history

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Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AHC_AHCT273_Q100 v.2	20200923	Product data sheet	-	74AHC_AHCT273_Q100 v.1				
Modifications:	of Nexperia. Legal texts have Section 2 update Table 4: Derating	been adapted to the n	ew company name w					
74AHC_AHCT273_Q100 v.1	20130327	Product data sheet	-	-				

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition		
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.		
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.		
Product [short] data sheet	Production	This document contains the product specification.		

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

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